CMOS Digital Integrated Circuits Silicon Monolithic

74VHCT540AFT,74VHCT541AFT

1. Functional Description

Octal Bus Buffer
74VHCT540AFT: INVERTED, 3-STATE OUTPUTS
74VHCT541AFT: NON-INVERTED, 3-STATE OUTPUTS

2. General

The 74VHCT540AFT and 74VHCT541AFT are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C²MOS technology. They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The $74\mathrm{VHCT540AFT}$ is an inverting type and, the $74\mathrm{VHCT541AFT}$ is a non-inverting type.

When either $\overline{G}1$ or $\overline{G}2$ are high, the terminal outputs are in the high-impedance state.

The input voltage are compatible with TTL output voltage.

These devices may be used as a level converter for interfacing 3.3 V to 5 V system.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

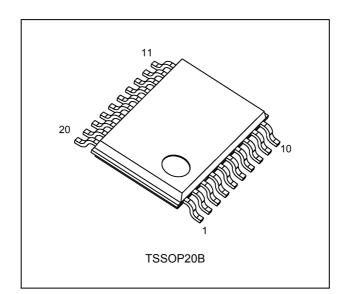
Note: Output in off-state

3. Features

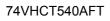
- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C
- (3) High speed: Propagation delay time = 5.4 ns (typ.) at V_{CC} = 5.0 V
- (4) Quiescent supply current: I_{CC} = 4.0 μ A (max) at T_a = 25 °C
- (5) Compatible with TTL input: $V_{IL} = 0.8 V (max)$
 - $V_{IH} = 2.0 V (min)$
- (6) Power down protection is provided on all inputs and outputs.
- (7) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (8) Low noise: $V_{OLP} = 1.5 V (max)$
- (9) Pin and function compatible with the 74 series (ACT/HCT/AHCT etc.) 540/541 type.
- Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

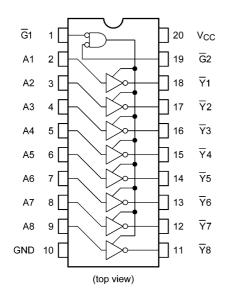
4. Packaging

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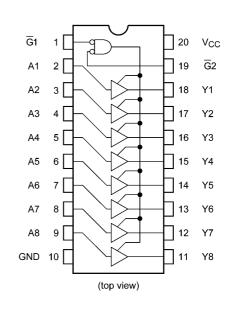


5. Pin Assignment

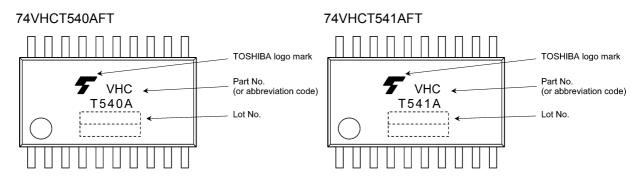




74VHCT541AFT



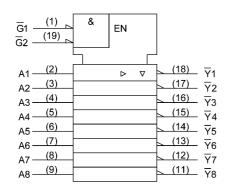
6. Marking



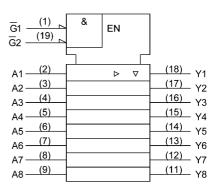
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7. IEC Logic Symbol

74VHCT540AFT



74VHCT541AFT



8. Truth Table

Input G1	Input G2	Input An	Output Yn	Output Yn
н	Х	Х	Z	Z
Х	Н	Х	Z	Z
L	L	Н	Н	L
L	L	L	L	Н

X: Don't care

Z: High impedance

Yn: 74VHCT541AFT

Yn: 74VHCT540AFT

9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to 7.0	1
Output voltage	V _{OUT}	(Note1)	-0.5 to 7.0	1
		(Note2)	-0.5 to V _{CC} + 0.5	1
Input diode current	I _{IK}		-20	mA
Output diode current	Ι _{ΟΚ}	(Note3)	±20	1
Output current	I _{OUT}		±25	1
V _{CC} /ground current	I _{CC}		±75	1
Power dissipation	P _D	(Note4)	180	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: Output in OFF state.

Note2: High (H) or Low (L) state. I_{OUT} absolute maximum rating must be observed.

Note3: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Note4: 180 mW in the range of $T_a = -40$ to 85 °C. From $T_a = 85$ to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		4.5 to 5.5	V
Input voltage	V _{IN}		0 to 5.5	
Output voltage	V _{OUT}	(Note1)	0 to 5.5	
		(Note2)	0 to V _{CC}	
Operating temperature	T _{opr}		-40 to 125	°C
Input rise and fall times	dt/dv		0 to 20	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note1: Output in OFF state.

Note2: High (H) or Low (L) state.

11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	—		4.5 to 5.5	2.0	_	_	V
Low-level input voltage	V _{IL}	—		4.5 to 5.5	_	_	0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	4.5	4.4	4.5	_	V
			I _{OH} = -8 mA	4.5	3.94	_	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	_	0.0	0.1	V
			I _{OL} = 8 mA	4.5	_	_	0.36	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND			_	_	±0.25	μΑ
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1	μA
Quiescent supply	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	_	4.0	μA
current	I _{CCT}	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	_	1.35	mA
Output leakage current (Power-OFF)	I _{OPD}	V _{OUT} = 5.5 V		0	_	_	0.5	μA

11.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	—		4.5 to 5.5	2.0	_	V
Low-level input voltage	VIL	_		4.5 to 5.5	_	0.8	V
High-level output voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -50 μA	4.5	4.4	—	V
			I _{OH} = -8 mA	4.5	3.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50μA	4.5	_	0.1	V
			I _{OL} = 8 mA	4.5	_	0.44	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5	_	±2.50	μA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±1.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	40.0	μA
Quiescent supply current	I _{ССТ}	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	1.50	mA
Output leakage current (Power-OFF)	I _{OPD}	V _{OUT} = 5.5 V		0	_	5.0	μΑ

11.3. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Conditio	Test Condition		Min	Max	Unit
High-level input voltage	V _{IH}	—		4.5 to 5.5	2.0	—	V
Low-level input voltage	VIL	—		4.5 to 5.5	_	0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	4.5	4.4	—	V
			I _{OH} = -8 mA	4.5	3.70	—	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 50 μA	4.5	_	0.1	V
			I _{OL} = 8 mA	4.5	_	0.55	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5	_	±10.0	μA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±2.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	80.0	μA
	I _{сст}	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	1.50	mA
Output leakage current (Power-OFF)	I _{OPD}	V _{OUT} = 5.5 V		0	_	20.0	μΑ

11.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	74VHCT540AFT	t _{PLH} ,t _{PHL}		_	5.0 ± 0.5	15	_	5.4	7.4	ns
						50	_	5.9	8.4	
	74VHCT541AFT	t _{PLH} ,t _{PHL}		—	5.0 ± 0.5	15	_	5.0	6.9	ns
						50	_	5.5	7.9	
3-state output enable time		t _{PZL} ,t _{PZH}		R _L = 1 kΩ	5.0 ± 0.5	15	_	8.3	11.3	ns
						50	_	8.8	12.3	
3-state output disable time		t _{PLZ} ,t _{PHZ}		$R_L = 1 k\Omega$	5.0 ± 0.5	50	_	9.4	11.9	ns
Output skew		t_{osLH}, t_{osHL}	(Note 1)	—	5.0 ± 0.5	50	_	—	1.0	ns
Input capacitance		C _{IN}		—			_	4	10	pF
Output capacitance		C _{OUT}		—			_	9		pF
Power dissipation capacitance		C _{PD}	(Note 2)	—			_	19	_	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|$, $t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per bit)

11.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	74VHCT540AFT	t _{PLH} ,t _{PHL}		—	5.0 ± 0.5	15	1.0	8.5	ns
						50	1.0	9.5	
	74VHCT541AFT	t _{PLH} ,t _{PHL}		—	5.0 ± 0.5	15	1.0	8.0	ns
						50	1.0	9.0	
3-state output enable time		t _{PZL} ,t _{PZH}		R _L = 1 kΩ	5.0 ± 0.5	15	1.0	13.0	ns
						50	1.0	14.0	
3-state output disable time		t _{PLZ} ,t _{PHZ}		$R_L = 1 k\Omega$	5.0 ± 0.5	50	1.0	13.5	ns
Output skew		t_{osLH}, t_{osHL}	(Note 1)	—	5.0 ± 0.5	50	_	1.0	ns
Input capacitance		C _{IN}		_			_	10	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

11.6. AC Characteristics

(Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	74VHCT540AFT	t _{PLH} ,t _{PHL}		—	5.0 ± 0.5	15	1.0	9.5	ns
						50	1.0	10.5	
	74VHCT541AFT	t _{PLH} ,t _{PHL}		—	5.0 ± 0.5	15	1.0	9.0	ns
						50	1.0	10.0	
3-state output enable time		t _{PZL} ,t _{PZH}		R _L = 1 kΩ	5.0 ± 0.5	15	1.0	14.5	ns
						50	1.0	15.5	
3-state output disable time		t _{PLZ} ,t _{PHZ}		$R_L = 1 k\Omega$	5.0 ± 0.5	50	1.0	15.0	ns
Output skew		t _{osLH} ,t _{osHL}	(Note 1)	_	5.0 ± 0.5	50	_	1.0	ns
Input capacitance		C _{IN}		_				10	pF

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$

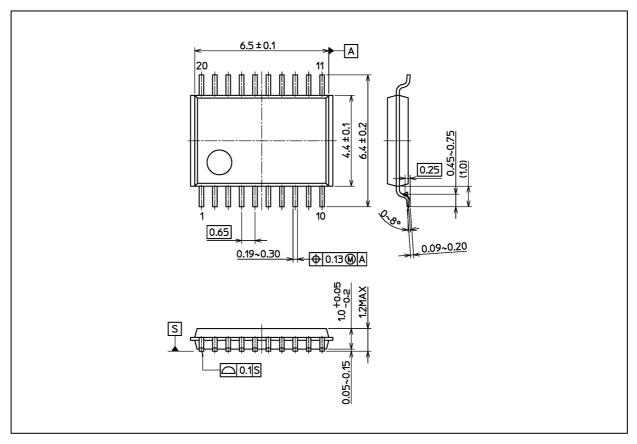
11.7. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	1.1	1.5	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-1.1	-1.5	
Minimum high-level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	_	2.0	
Maximum low-level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0		0.8	



Package Dimensions

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)
Nickname: TSSOP20B	

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